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Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.140 inches all semiconductor device diode and 0.180 inches all semiconductor device diode

Terminal Length:

1.000 inches all semiconductor device diode and 1.500 inches all semiconductor device diode

Overall Diameter:

0.056 inches all semiconductor device diode and 0.075 inches all semiconductor device diode

Function For Which Designed:

Switching

End Application:

5841-01-236-8951 detecting set r an/apr-39 (v) 1

Internal Configuration:

Junction contact all semiconductor device diode

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-35 all semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Matched

Component Name And Quantity:

2 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Features Provided:

Hermetically sealed case and electrostatic sensitive

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

50.0 working peak reverse voltage, peak total value all semiconductor device diode

Current Rating Per Characteristic:

225.00 milliamperes source cutoff current preset all semiconductor device diode and 75.00 milliamperes forward current, average absolute all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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